N on-equilibrium Born-Oppenheim er potential energy surfaces for molecular wires

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W e present a m ethod for com puting non-equilibrium, current-dependent B om-O ppenheim er potential energy surfaces for m olecular w ires. C alculations are perform ed for polyacetylene w ire described by tight-binding m odel w ith electron-phonon interactions. W e nd that dim erization of the polyacetylene w ire is am pli ed by electric current ow. W e show that the boundary between transparent and opaque black states of the w ire is blue-shifted by current.

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One of the major goals in modern nanotechnology is the construction of an electronic circuit in which molecular system s act as conducting element [1]. Two critical issues should be thoroughly investigated to proceed with the design of realm olecular devices: heating in a m olecular junction and current induced conform ational changes of a junction caused by electrom igration. By the inelastic scattering of electrons the kinetic energy of current is transfered to the nuclear vibrations and then it is released asheat. The second process, electrom igration, is the phenom enon of atom motion due to current induced forces and it is related to the transfer of electronic m om entum to nucleidue to both elastic and inelastic scattering. The electrom igration can lead to device breakdown at criticalvalues of current and therefore current-induced forces m ay present a lim itation for the developm ent of m olecular electronic devices. Very recently, controlled electrom igration has been used constructively to make a singlem olecular junction [2]. Both issues, heating and electrom igration, are ultim ately related to understanding how Bom-Oppenheimer (BO) potential energy surface of a molecular wire is responded to electronic current ow. If current-dependent BO potential energy surface of a molecular device is available, we can compute currentinduced forces as the corresponding gradients as well as we can perform the norm alm odes analysis to obtain the current-dependent vibrations.

A lthough the practical importance of a currentdependent BO surface can not be underestim ated, som e intricate theoretical questions connected to the di culty in de ning a generic variational energy functional for non-equilibrium steady state systems [3, 4, 5] can be also puzzled out. Theoretical work to date has failed to de ne or even to prove the existence of the BO potential energy surface form olecular wires with current ow. The principle theoretical di culty is the treatment of the transport problem as an electron transmission (Landauer approach [6]) which is non-variational from the outset. A wire with current is by de nition an open quantum system and as long as one works within a non-variational transport theory it is likely not possible to comprise a geom etrical optim ization of the nuclear degrees of freedom with electronic transport calculations within a single theoretical approach. There is the opinion that current induced forces can not be conservative [7] although validity of this claim has been recently questioned [8]. If a current induced force is not conservative then there does not exist a BO potential energy surface of which this force m ight be derivative. O ne of the goals of this Letter is to show that this is not true and that the B om-O ppenheim er potential energy surface can be properly de ned and e ciently computed in the presence of current ow.

The Lagrange multiplier based transport theory [9, 10] takes its origin in them odern developm ent of steady state non-equilibrium statistical mechanics [11, 12, 13]. This theory is equivalent to a variational formulation where the constrained m in im ization of the expectation value of the Ham iltonian on the manifold of the desired current J yields the transport properties [9]. The \algorithm " of the Lagrange multiplier based transport theory to com pute a current-dependent BO surface can be sum m arized as follows: (1) de ne the operator of the current J via the continuity equation; (2) extend the Ham iltonian H by adding the term (J) where is a Lagrange multiplier; (3) compute the BO surface as the expectation value h0() H D() iwhere D() is the \ground state" of the extended H am iltonian H J.

In this Letter, using the Lagrange multiplier based transport theory we com pute the current-dependent BO potential energy surfaces of conjugated polymer, polyacetylene, wire. Polyacetylene is a linear polymer, it consists of coupled chain of CH units forming a quasione-dimensional lattice. Each C has four valence electrons: two of them contribute to the -type bonds connecting neighboring carbons along the one-dimensional backbone, while the third form s a bond with the the hydrogen. The remaining electron has the symmetry of a $2p_z$ orbital and contributes to -bond. In terms of the energy band description, the -bonds form low -lying completely lled band, while -bond leads to half- lled energy band responsible for electron transport properties. The -electrons can to a fair approximation be treated as a quasi-one dim ensional electron gas within the tight-

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binding approximation. A coordingly, we start our consideration from the following model electronic Ham iltonian for the polymer chain

$$H = \begin{pmatrix} X \\ (t_{o} + (1)^{n} x) (a_{n+1}^{y} a_{n} + a_{n}^{y} a_{n+1}) \\ + 2N K x^{2} : \qquad (1)$$

Here a_n creates an electron of spin on site n. The Ham iltonian H is based upon the so called Su-Schrie er-Heeger (SSH) [14] model for the band-structure of trans-(CH)_n lattices. The rst term in the H gives the energy for an electron with spin to hop between neighboring p_z -orbitals. The strength of this term is modulated by linear coupling to distortions x in the polymer lattice away from evenly spaced lattice positions. Finally, the last term s in H gives the harm onic interactions between lattice-sites arising from the -bonds between neighboring lattice atom s.

We begin the derivation by dening the operator of current via continuity equation. The number of electrons on the site n is given by the expectation value of the operator

$$N_n = \begin{array}{c} X \\ a_n^y a_n \end{array} \qquad (2)$$

By making use of the Heisenberg representation the continuity equation can be written as the Heisenberg equation-ofmotion for the operator N_n :

$$N_{n} = i \left[H_{o}; N_{n} \right] :$$
 (3)

G iven standard anti-commutation relations between the electron creation and annihilation operators, the rh.s. commutator (3) can be readily computed. Comparing eq.(3) with the nite di erence expression for continuity equation $N_n = (j_n \ j_n \ 1)$ we obtain the de nition of the operator of current through site n. By making the sum of on-site currents j_n along the wire we de ne the net, m acroscopic current through the wire

$$J = i \int_{n}^{X} (t_{o} + (1)^{n} x) (a_{n+1}^{y} a_{n} a_{n+1}^{y}) (a_{n+1}^{y} a_{n+1}) (4)$$

There are two distinct contributions to the net current. The term $t_o\,(a_{n+1}^y\ a_n\ a_n^y\ a_{n+1}\)$ is the standard for molecular wires without electron-phonon coupling whereas the term ($1)^n\ x\,(a_{n+1}^y\ a_n\ a_n^y\ a_{n+1}\)$ is the phonon-assisted current.

W e assume now that there is a time-independent, constant current through the wire. A hom ogeneous currentcarrying state is the same whether it is introduced by reservoirs or by a bulk driving driving eld, the current enters the problem via a Lagrange multiplier . To this end the Ham iltonian H is modiled by adding the term which constraints the macroscopic current J:

$$H_{J} = H \qquad J :$$
 (5)

The H am iltonian H $_{\rm J}$ is a quadratic form in ferm ion creation/annihilation operators. This quadratic form can be exactly diagonalized by two unitary transform ations. The Fourier transform ation

$$a_n = \frac{1}{N} \sum_{k}^{X} \exp(ikn)c_k ; \qquad (6)$$

brings the H am iltonian (5) to the following form

$$H_{J} = \begin{array}{cccc} X & X \\ H_{J} = \begin{array}{cccc} X & X \\ & C_{k+} \\ 0 & k < 2 \end{array} \qquad k & k \\ & K & k \\ & K & K \\ & K & C_{k} \end{array}$$
(7)

 ${\tt W}$ e have introduced here the phonon-unperturbed band energy

$$_{k}() = 2t_{0}(\cos(k) + \sin(k));$$
 (8)

and the phonon-induced gap

$$_{k}(;x) = 4 x (sin (k) cos(k)):$$
 (9)

Both quantities, $_k$ () and $_k$ (;x) depend upon current via the Lagrange multiplier and if we let tend to zero we recover the usual zero-current results [14]. M ixing q_k and q_{k+} operators by the canonical B ogoliubov transform ation

we obtain new quasipaticles $_k$ and $_{k+}$. The coe cients of the Bogoliubov transform ation is chosen in such a way that the extended H am iltonian (7) should be diagonal. It leads to the following expressions for the coe cients

$$u_{k} = \frac{p_{(k)}}{(k)} \cos(k) \qquad p_{(k)} \sin(k); \qquad (11)$$

$$v_k = \frac{p_{(k)}}{(k)} \sin(k) + \frac{p_{(k)}}{1} \cos(k);$$
 (12)

where $(_k)$ is the H eaveside step function and the mixing angle $_k$ is given by the form ula $_k = 1=2 \arctan(_k = _k)$. This canonical B oguluibov transform ation produces the non-interacting H am iltonian for the quasiparticles $_k$ and $_{k+}$:

$$H_{J} = \begin{matrix} X & X \\ E_{k} \begin{pmatrix} y \\ k^{+} \end{pmatrix} \\ 0 & k^{-} \\ + & 2N K x^{2}; \end{matrix}$$
(13)

with the wave-vector k in the reduced Brillouin zone of the system. The band energy, $E_k = \frac{2}{k} + \frac{2}{k}$, and the mixing angle k in the canonical Bogoliubov transform ation are functions of the phonon-unperturbed band energy, k(), and the phonon-induced energy gap, k(;x).

It can be straitforwardly shown that this diagonalization of the Ham iltonian is equivalent to the variational

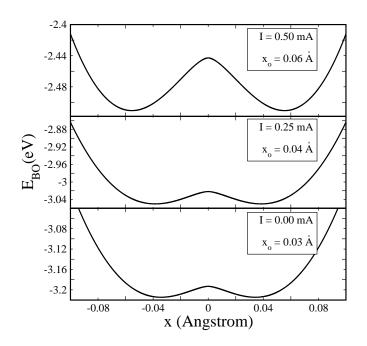


FIG.1: Bom-Oppenheim er potential energy surfaces for different values of the current: I=0.00 mA (low er panel), I=0.25 mA (m iddle panel) and I=0.50 mA (upper panel). The dim erization coordinate, $x_{\rm o}$, corresponds to the m inimum on the BO surface and it is shown for each values of the current.

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problem hH Ji = 0 with the coe cients of the Bogoliubov transform ation u_k and v_k as variational param – eters. Current carrying steady states are by de nition the ground states of extended, current dependent H am iltonian H_J [9]. The ground state of the H am iltonian (13) can be de ned as the vacuum state for quasiparticle $_{k+}$ and $_{k}^{y}$. All physical properties of the system depend upon the current and can be obtained as the matrix element of the corresponding operators over the current carrying \ground state" J() () i. Now the non-equilibrium B om-O ppenheim er potential energy surface is de ned as the expectation value of the original H am iltonian H (1) over the current carrying wave function:

$$E_{BO}(;x) = h0() H D()i$$

= 2 E_k(;x) + 2N K x² (14)

The band energy E_k , the mixing angles $_k$, and the current carrying wave function j0 () i are not yet in a form to be computed as the Lagrange multiplier is not known yet. The additional equation for the Lagrangian multiplier is obtained if the density of an expectation value of the net current operator (4) over the current carrying state of the H am iltonian (13) is required to yield a desired current density I. This sets up the continuity equation:

$$\frac{1}{N}h0()jJj0()i = \frac{2}{N} \frac{X}{_{0,k\leq}} (2("_k) - 1)(2t_0 \sin(k)\cos(2_k) + 4x\cos(k)\sin(2_k)) = I$$
(15)

For any given lattice distortion x the nonlinear equation (15) should be resolved for \cdot . Then the band energy and the mixing angle $_k$ of the canonical B ogoliubov transform ations are computed as functions of current.

We now discuss the main results obtained using the above model. The numerical calculations are performed for the half-occupied conductance band with the box length N = 1000. In all our calculations we use the following model parameters of the SSH model [15]: $t_0 = 2.5$ eV, = 4.1 eV, and K = 21 eV=A². This parameterization of the ASH H am iltonian is typically used to describe coherent electron transport in polyacetylene wire [15].

In the rst calculations, shown in Fig.1, we studied the changes of the BO surface as current ows through the wire. It is immediately evident from Fig.1 that the current substantially alters the Born-Oppenheimer potential energy surface of the polyacetylene wire. The minima on the BO surface correspond to the optimal non-equilibrium steady state geometries of the wire. The dimerization coordinate increases as current ows, i.e. the C = C double bonds are shortened and the C C

single bonds are elongated by the current induced forces. By increasing the current we also increase the barrier between the two-fold degenerate ground states, therefore the energy di erence between evenly spaced polyacetylene and dim erized polyacetylene is increased as we increase the current. Since SSH Ham iltonian is very general and applicable in its present formulation to any long sem iconductor wires we do expect that e ect of the current-ampli ed dim erization occurs in other quasione-dimensional wires as well. The results of our calculations are qualitatively consistent with the nding of Todorov, Hoekstra and Sutton [16] that current-induced forces generally form an alternating patterns in atom ic wires. The critical value of the current at which the current induced forces break the wire into pieces can be also determ ined. If we assume that the current-induced bond distortion larger than 0.2A will be su cient to rupture the wire, the critical value of the current which the polyacetylene wire can sustain is 0.8 m A.

Finally, we turn our attention towards what physical quantities which are accessible experimentally can

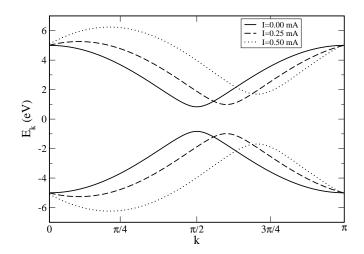


FIG. 2: The current-dependent valence and conductance bands of polyacetylene wire, $E_k = \frac{1}{k} + \frac{2}{k}$.

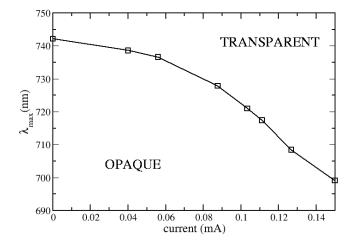


FIG. 3: The transparent-opaque boundary for polyacetylene wire as a function of current

be used to monitor the current-ampli ed polyacetylene

dimerization. To this end we compute the response of the band structure of polyacetylene to current ow. The current-dependent band structure of the rst Brillouin zone is plotted in Fig2. Polyacetylene's band is half occupied therefore the states with negative E_k are completely occupied and the states with positive E_k are empty. The current ow through the wire does not only produce the overall shift of the band energy within the reduced Brillouin zone but also changes the the total bandwidth from 10 eV at zero current to 12.5 eV at I = 0.5 m A. The band gap between the valence and conductance bands is also modulated by current.

From the band structure calculations the band gap can be extracted as a function of the current. Then the band gap can be turned into the longest possible wavelength of absorbed radiation $_{m ax}$ and this is plotted in Fig.3 for di erent values of the net current density. Being a sem iconductor wire, polyacetylene is transparent to the photons with wave length longer than $_{m ax}$ (i.e. with the energies within the band gap) but it is opaque to photons with wavelength shorter than $_{m ax}$ (within the bandwidth). It is clear from that the boundary between transparent and opaque black parts of the spectrum is blue-shifted by current ow in the polyacetylene wire. In other words, the color of the polyacetylene wire can be m odi ed by electric current.

In this Letter, we have laid a theoretical ground-work for com puting a B om-O ppenheim er potential energy surface for m olecular wires with direct current. W ithin the Lagrange multiplier based transport theory we presented a com putational tractable theoretical scheme to com pute BO ofm olecular wire junctions. B ased upon applications of the techniques to tight-binding m odel with electronphonon interactions we predict that (1) the dim erization of the polyacetylene wire is am plied by current; (2) the transparent-opaque boundary is blue-shifted by current ow; (3) the generic mechanism of the sem iconductor wire

breakage is current increased dim erization.

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- [1] A.N itzan and M.A.Ratner, Science 300, 1384 (2003).
- [2] W J. Liang, M P. Shores, M Bockrath, JR Long, and H Park, Nature 417, 725 (2002).
- [3] T N. Todorov, J H oekstra and A P. Sutton, Phylos. M ag. B 80, 421 (2000)
- [4] M. D iVentra and S.T. Pantelides, PhysRev B 61, 16207 (2000).
- [5] E.G. Emberly and G.K irzenow, PhysRev.B 64, 125318 (2001)
- [6] R Landauer, Philos. M ag. 21, 863 (1970).
- [7] R S. Sorbello, Solid State Physics (A cadem ic Press, New York, 1998), Vol.51.
- [8] M. Di Ventra, Yu-Chang Chen, T.N. Todorov, condm at/0307739
- [9] D S.Kosov, J.Chem Phys. 116, 6368 (2002).

- [10] D.S. Kosov, J.Chem Phys., submitted (condmat/0309583)
- [11] T Antal, Z Racz, and L Sasvari, PhysRev Lett. 78, 167 (1997).
- [12] T Antal, Z Racz, A Rakos, and G M Schutz PhysRev.E, 59, 4912 (1999).
- [13] V E isler, Z R acz, and F .van W ijland, PhysRev.E, 67, 056129 (2003).
- [14] A.J.Heeger, S.Kivelson, J.R.Schrie er, and W.P.Su, Rev M od Phys. 60, 781 (1988).
- [15] H. Ness, S. A. Shevlin, and A. J. Fisher, Phys. Rev. B 63, 125422 (2001).
- [16] T N. Todorov, J. Hoekstra, and A P. Sutton, PhysRevLett. 86, 3606 (2001).